

PATENT APPLICATION

N'HE UNITED STATES PATENT AND TRADEMARK OFFICE

| In Re U.S. Patent Application | |) | I hereby certify that this paper is being deposited with the United States Postal Service as FIRST-CLASS mail | 7/11/0 | |
|--|-------------------|---|--|-------------------------|-----|
| Applicant: | Hongyong Zhang |) | in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on this date. Date Registration No. 47, 9571 | | |
| Serial No. | 09/468,489 |) | | Registration No. 47,954 | |
| Filed: | December 20, 1999 |) | F-CLASS.WCM Appr. February 20, 1998 | Attorney for Applicant | |
| For: THIN FILM TRANSISTOR HAVING LIGHTLY AND HEAVILY DOPED SOURCE/ DRAIN REGIONS AND ITS MANUFACTURE | |) | | | |
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| | |) | | JUL 10 | ECE |
| Art Unit: | 2814 |) | | X CENT | |
| Examiner: | Quanch, T. |) | | LER 28 | |
| AMENDMENT A | | | | | |

Assistant Commissioner for Patents Washington, D.C. 20231

Dear Sir:

In response to the office action mailed January 30, 2001, please amend the above-identified Application as follows:

IN THE CLAIMS:

Please enter amended claims 1, 3, and 5 as follows: